SN75471 THRU SN75473 DUAL PERIPHERAL DRIVERS

SLRS024 - DECEMBER 1976 - REVISED MAY 1990

PERIPHERAL DRIVERS FOR HIGH-VOLTAGE HIGH-CURRENT DRIVER APPLICATIONS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 55 V (After Conducting 300 mA)
- Medium-Speed Switching
- Circuit Flexibility for Varied Applications and Choice of Logic Function
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame Provides Cooler Operation and Improved Reliability

SUMMARY OF SERIES SN75471

DEVICE	LOGIC OF COMPLETE CIRCUIT	PACKAGES
SN75471	AND	D, P
SN75472	NAND	D, P
SN75473	OR	D, P

description

Series SN75471 dual peripheral drivers are functionally interchangeable with series SN75451B and series SN75461 peripheral drivers, but are designed for use in systems that require higher breakdown voltages than either of those series can provide at the expense of slightly slower switching speeds than series 75451B (limits are the same as series SN75461). Typical applications include high-speed logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN75471, SN75472, and SN75473 are dual peripheral AND, NAND, and OR drivers, respectively, (assuming positive logic), with the output of the logic gates internally connected to the bases of the npn output transistors.

Series SN75471 drivers are characterized for operation from 0°C to 70°C.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1)	7 V
Input voltage, V _I	
Inter-emitter voltage (see Note 2)	5.5 V
Off-state output voltage, V _O	70 V
Continuous collector or output current (see Note 3)	400 mA
Peak collector or output current ($t_W \le 10$ ms, duty cycle $\le 50\%$, see Note 3)	500 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. Voltage values are with respect to the network GND, unless otherwise specified.

- 2. This is the voltage between two emitters, A and B.
- 3. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW
Р	1000 mW	8.0 mW/°C	640 mW

recommended operating conditions

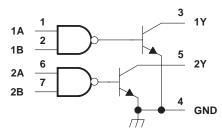
	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.75	5	5.25	V
High-level input voltage, VIH	2			V
Low-level input voltage, V _{IL}			0.8	V
Operating free-air temperature, TA	0		70	°C



logic symbol†

1A $\frac{1}{2}$ & \bigcirc 1Y 2A $\frac{6}{7}$ 25 2Y

logic diagram (positive logic)

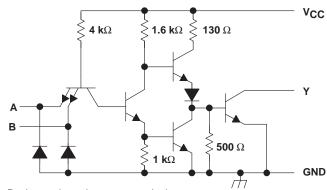


SN75471 FUNCTION TABLE (each driver)

Α	В	Υ
L	L	L (on state)
L	Н	L (on state)
Н	L	L (on state)
Н	Н	H (off state)

positive logic: $Y = AB \text{ or } A + \overline{B}$

SN75471 schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

DADAMETER			SN75471			
	PARAMETER	TEST CONDITIONS	MIN	TYP [‡]	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = 4.75 \text{ V}, I_{I} = -12 \text{ mA}$		-1.2	-1.5	V
loh	High-level output current	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{OH} = 70 \text{ V}$			100	μΑ
\/a.	Low level output veltage	$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 100 \text{ mA}$		0.25	0.4	V
VOL	Low-level output voltage	$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 300 \text{ mA}$		0.5	0.7	V
Ιį	Input current at maximum input voltage	$V_{CC} = 5.25 \text{ V}, V_I = 5.5 \text{ V}$			1	mA
lн	High-level input current	$V_{CC} = 5.25 \text{ V}, V_I = 2.4 \text{ V}$			40	μΑ
IIL	Low-level input current	$V_{CC} = 5.25 \text{ V}, V_I = 0.4 \text{ V}$		-1	-1.6	mA
ICCH	Supply current, outputs high	V _{CC} = 5.25 V, V _I = 5 V		7	11	mA
ICCL	Supply current, outputs low	$V_{CC} = 5.25 \text{ V}, V_{I} = 0$		52	65	mA

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS		SN75471			UNIT
	PARAMETER			MIN	TYP	MAX	UNII
tPLH	Propagation delay time, low-to-high-level output				30	55	
tPHL	Propagation delay time, high-to-low-level output	I _O ≈ 200 mA,			25	40	20
tTLH	Transition time, low-to-high-level output	$R_L = 50 \Omega$,	See Figure 1		8	20	ns
tTHL	Transition time, high-to-low-level output]			10	20	
VOH	High-level output voltage after switching	V _S = 55 V, See Figure 2	$I_O \approx 300 \text{ mA},$	V _S -18			mV



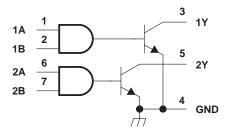
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

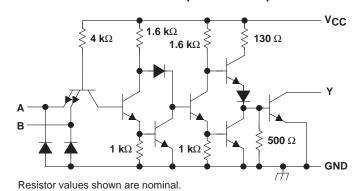


SN75472 FUNCTION TABLE (each driver)

Α	В	Υ
L	L	H (off state)
L	Н	H (off state)
Н	L	H (off state)
Н	Н	L (on state)

positive logic: Y = AB or A + B

SN75472 schematic (each driver)



electrical characteristics over recommended operating free-air temperature range

	PARAMETER	TEST CONDITIONS	SN75472			UNIT
	PARAMETER	TEST CONDITIONS	MIN	TYP [‡]	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = 4.75 \text{ V}, I_{I} = -12 \text{ mA}$		-1.2	-1.5	V
loh	High-level output current	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{OH} = 70 \text{ V}$			100	μΑ
V/01	Low-level output voltage	$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 100 \text{ mA}$		0.25	0.4	V
VOL		$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 300 \text{ mA}$		0.5	0.7	
Ц	Input current at maximum input voltage	$V_{CC} = 5.25 \text{ V}, V_{I} = 5.5 \text{ V}$			1	mA
ΙΗ	High-level input current	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.4 \text{ V}$			40	μΑ
I _{IL}	Low-level input current	$V_{CC} = 5.25 \text{ V}, V_{I} = 0.4 \text{ V}$		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = 5.25 \text{ V}, V_{I} = 5 \text{ V}$		13	17	mA
ICCL	Supply current, outputs low	$V_{CC} = 5.25 \text{ V}, V_{I} = 0$		61	76	mA

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CONDITIONS		SN75472			UNIT
	PARAMETER			MIN	TYP	MAX	ONIT
tPLH	Propagation delay time, low-to-high-level output				45	65	
tPHL	Propagation delay time, high-to-low-level output	I _O ≈ 200 mA, 0	C _L = 15 pF,		30	50	ns
^t TLH	Transition time, low-to-high-level output	$R_L = 50 \Omega$,	See Figure 1		13	25	115
^t THL	Transition time, high-to-low-level output				10	20	
Vон	High-level output voltage after switching	V _S = 55 V, See Figure 2	I _O ≈ 300 mA,	V _S -18		·	mV

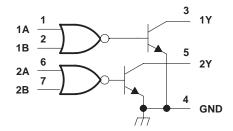


logic symbol†

≥1 ⊳ 2 1B 6 2A 7 2B

[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

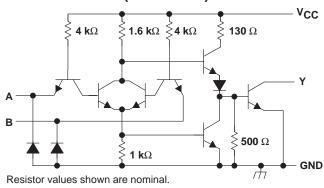


FUNCTION TABLE (each driver)

Α	В	Υ
L	L	L (on state)
L	Н	H (off state)
Н	L	H (off state)
н	Н	H (off state)

positive logic: $Y = A + B \text{ or } \overline{A} \overline{B}$

schematic (each driver)



electrical characteristics over recommended operating free-air temperature range

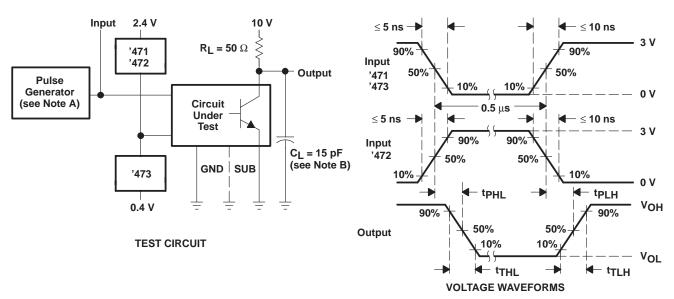
	24244555	TEST SOMBITIONS	SN75473			
	PARAMETER	TEST CONDITIONS		TYP‡	MAX	UNIT
٧IK	Input clamp voltage	$V_{CC} = 4.75 \text{ V}, I_{I} = -12 \text{ mA}$		-1.2	-1.5	V
loh	High-level output current	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{OH} = 70 \text{ V}$			100	μΑ
\/a.	Low-level output voltage	$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 100 \text{ mA}$		0.25	0.4	V
VOL		$V_{CC} = 4.75 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 300 \text{ mA}$		0.5	0.7	V
Ι _Ι	Input current at maximum input voltage	$V_{CC} = 5.25 \text{ V}, V_{I} = 5.5 \text{ V}$			1	mA
ΙΗ	High-level input current	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.4 \text{ V}$			40	μΑ
I _I L	Low-level input current	$V_{CC} = 5.25 \text{ V}, V_{I} = 0.4 \text{ V}$		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = 5.25 \text{ V}, V_{I} = 5 \text{ V}$		8	11	mA
ICCL	Supply current, outputs low	$V_{CC} = 5.25 \text{ V}, V_{I} = 0$		58	76	mA

[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		SN75473			UNIT
				MIN	TYP	MAX	ONII
^t PLH	Propagation delay time, low-to-high-level output	$I_{\mbox{O}} \approx 200 \mbox{ mA},$ $R_{\mbox{L}} = 50 \Omega,$	See Figure 1		30	55	ns
t _{PHL}	Propagation delay time, high-to-low-level output				25	40	
tTLH	Transition time, low-to-high-level output				8	25	
tTHL	Transition time, high-to-low-level output				10	25	
VOH	High-level output voltage after switching	V _S = 55 V, See Figure 2	$I_O \approx 300 \text{ mA},$	V _S -18		·	mV

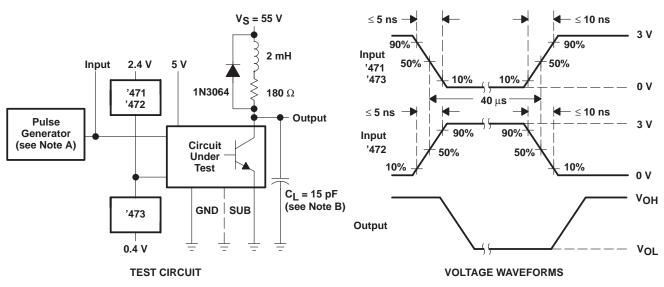
PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: PRR \leq 1 MHz, $Z_{\mbox{O}}\approx$ 50 Ω

B. C_L includes probe and jig capacitance.

Figure 1. Switching Times



NOTES: A. The pulse generator has the following characteristics: PRR \leq 12.5 kHz, $Z_{O} \approx 50 \Omega$.

B. C_L includes probe and jig capacitance.

Figure 2. Latch-Up Test



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